anasonic

Standard type: c \(\text{Vis} \) Reinforced type: c \(\text{Vis} \) \(\text{Us} \)

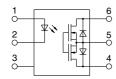




Normally closed DIP6-pin type Low on-resistance with 250V/400V load voltage $PhotoMOS^{\circ}$ HE 1 Form B (AQV45O, AQV454H)



mm inch

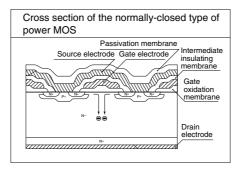


RoHS compliant

FEATURES

1. 1 Form B (Normally-closed) type with low on-resistance

This has been achieved thanks to the built-in MOSFET processed by our proprietary method, DSD (Doublediffused and Selective Doping) method.



2. Controls low-level analog signals PhotoMOS feature extremely low closedcircuit offset voltage to enable control of low-level analog signals without distortion.

3. High sensitivity and low onresistance

Can control max. 0.2 A load current with 5 mA input current. Low on-resistance of Typ. 5.5 Ω (AQV453).

4. Reinforced insulation 5,000 Vrms type also available.

More than 0.4 mm .016 inch internal insulation distance between inputs and outputs. Conforms to IEC950 (reinforced insulation).

TYPICAL APPLICATIONS

- Security equipment
- High-speed inspection machines
- Measuring instruments
- Telephone equipment
- Sensing equipment

TYPES

	I/O isolation	Output rating*				Par				
		Load voltage	Load current	Package -	Through hole terminal				Packing quantity	
					Tube packing style		Tape and reel	packing style	Tube	Tape and reel
							Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
AC/DC dual use	1,500 Vrms	250 V	200 mA		AQV453	AQV453A	AQV453AX	AQV453AZ	1 tube contains:	1,000 pcs.
		400 V 150 m/	150 mA	DIP6-pin	AQV454	AQV454A	AQV454AX	AQV454AZ	50 pcs. 1 batch contains:	
	Reinforced 5,000 Vrms	400 V	150 IIIA		AQV454H	AQV454HA	AQV454HAX	AQV454HAZ	500 pcs.	

-1-

Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

^{*} Indicate the peak AC and DC values.

RATING

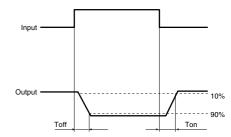
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV453(A)	AQV454(A)	AQV454H(A)	Remarks	
Input	LED forward current	lF		50 mA				
	LED reverse voltage	VR	1 \	5 V				
	Peak forward current	IFP		1 A			f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin		75 mW				
Output	Load voltage (peak AC)	V∟	1 \	250 V	400 V			
			Α	0.2 A	0.15 A 0.18 A		A connection: Peak AC, DC B. C connection: DC	
	Continuous load current	l∟	В	0.3 A				
			С	0.4 A	0.25 A		B, O conficction. Bo	
	Peak load current	IPEAK		0.6 A	0.5 A		A connection: 100 ms (1 shot), V _L = DC	
	Power dissipation	Роит		360 mW				
Total power dissipation		Р⊤] \ [410 mW				
I/O isolation voltage		Viso] \ [1,500 Vrms 5,000 Vrms				
Ambient temperature	Operating	Topr		-40 to +85°C −40 to +185°F		-40 to +85°C -40 to +185°F (Non-icing at low temperat		(Non-icing at low temperatures)
	Storage	Tstg		-40 to +100°C −40 to +212°F				

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item				Type of connection	AQV453(A)	AQV454(A)	AQV454H(A)	Condition	
Input	LED operate (OFF) current	Typical	Foff		1 mA	0.9 mA	1.4 mA	I∟ = Max.	
	LED operate (OFF) current	Maximum	IFoff	_ [3 mA			TIL = Max.	
	LED reverse (ON) current	Minimum	l _{Fon}			I∟ = Max.			
	LED reverse (ON) current	Typical	IFON		0.9 mA	0.8 mA	1.3 mA	IL = IVIAX.	
	LED dropout voltage	Typical	VF	_	1.2	I _F = 50 mA			
	LED dropout voitage	Maximum	VF		1.5 V				
		Typical	Ron	A	5.5 Ω	11 Ω		IF = 0 mA IL= Max. Within 1 s	
	On resistance	Maximum			8 Ω	16 Ω			
		Typical	Ron	В	2.7 Ω	6.3 Ω		I _F = 0 mA I _L = Max. Within 1 s	
Output		Maximum			4 Ω	8 Ω			
·		Typical	Ron	С	1.4 Ω	3.1 Ω		I _F = 0 mA I _L = Max. Within 1 s	
		Maximum	H ion		2 Ω	4 Ω			
	Off state leakage current	Maximum	Leak	_	1 μΑ	1 μΑ	10 μΑ	I _F = 5 mA V _L = Max.	
Transfer characteristics	Operate (OFF) time*	Typical	off	_	1.52 ms	1.2 ms	1.8 ms	I _F = 0 mA → 5 mA	
	Operate (OFF) time*	Maximum			3 ms	2.0 ms	3.0 ms	I∟ = Max.	
	D	Typical	_	_	0.4 ms	0.36 ms	0.4 ms	I _F = 5 mA → 0 mA	
	Reverse (ON) time*	Maximum	Ton		1 ms			I∟ = Max.	
	I/O capacitance	Typical	Ciso	_		f = 1 MHz			
	I/O capacitance	Maximum	Ciso		3 pF			V _B = 0 V	
	Initial I/O isolation resistance	Minimum	Riso	_	1,000 MΩ		500 V DC		

*Operate/Reverse time



3. Recommended operating conditions (Ambient temperature: $25^{\circ}C$ $77^{\circ}F$)

Please use under recommended operating conditions to obtain expected characteristics.

	Item	Symbol	Min.	Max.	Unit
	LED current	lF	5	30	mA
AQV453(A)	Load voltage (Peak AC)	VL	_	200	V
	Continuous load current (A connection)	lı.	_	0.2	Α
AQV454(A)	Load voltage (Peak AC)	VL	_	320	V
	Continuous load current (A connection)	lı.	_	0.15	Α
AQV454H(A)	Load voltage (Peak AC)	VL	_	320	V
	Continuous load current (A connection)	l.	_	0.15	Α

■ These products are not designed for automotive use.

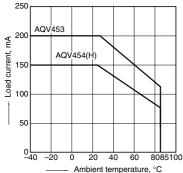
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

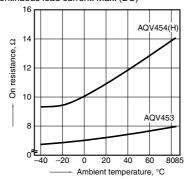
Allowable ambient temperature: -40 to +85°C -40 to +185°F

Type of connection: A



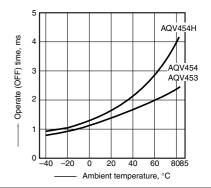
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6; LED current: 0 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



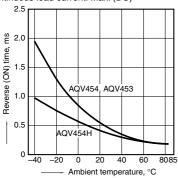
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



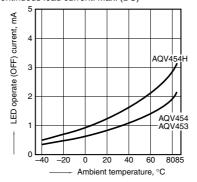
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



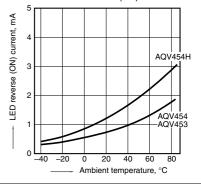
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: Max. (DC); Continuous load current: Max. (DC)

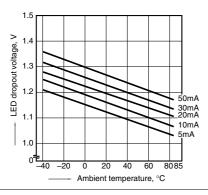


6. LED reverse (ON) current vs. ambient temperature characteristics Load voltage: Max. (DC);

Continuous load current: Max. (DC)

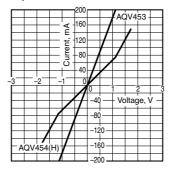


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



8. Current vs. voltage characteristics of output at MOS portion

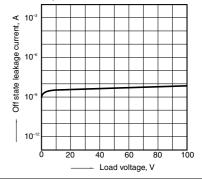
Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



9. Off state leakage current vs. load voltage characteristics

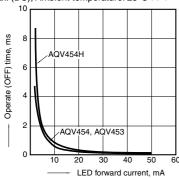
Sample: AQV454:

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



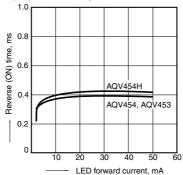
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



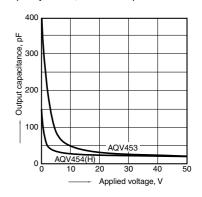
11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6; Frequency: 1 MHz; Ambient temperature: 25°C 77°F



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Please contact

Panasonic Corporation Electromechanical Control Business Division

■ 1006, Oaza Kadoma, Kadoma-shi, Osaka 571-8506, Japan industrial.panasonic.com/ac/e/



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